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## MMSZ4697

### General Description

Half watt, General purpose, Medium Current Surface Mount Zener in the SOD-123 package. The SOD-123 package has the same footprint as the glass mini-melf (LL-34) package & provides a convenient alternative to the Leadless package.

### Features

- Compact surface mount with same footprint as mini-melf
- 500mW rating on FR-4 or FR-5 board.
- Class 3 ESD rating (>16kV) per Human Body Model

### Ordering

- 7 inch reel (178mm); 8mm Tape; 3,000 units per reel.

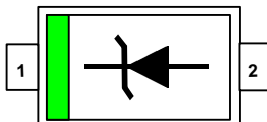
### Absolute Maximum Ratings (Note 1) $T_A=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$T_{STG}$	Storage Temperature	-55 ~ 150	$^\circ\text{C}$
$T_J$	Maximum Junction Temperature	-55 ~ 150	$^\circ\text{C}$
$P_D$	Total Power Dissipation at $25^\circ\text{C}$ Derate above $25^\circ\text{C}$	500 6.7	mW mW/ $^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient	340	$^\circ\text{C}/\text{W}$
$R_{\theta JL}$	Thermal Resistance Junction to Lead	150	$^\circ\text{C}/\text{W}$
$\Delta V_Z$	Maximum Voltage Change (Note 2)	100	mV
Lead Solder Temperature (Max 10 second duration)		260	$^\circ\text{C}$
Nominal Zener Voltage ( $V_Z$ ) at $50\mu\text{A}$		10	V

Note 1: These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Note 2: Voltage change is equal to the difference between  $V_Z$  at  $100\mu\text{A}$  and  $V_Z$  at  $10\mu\text{A}$ .

Top Mark: DE  
1: Cathode  
2: Anode

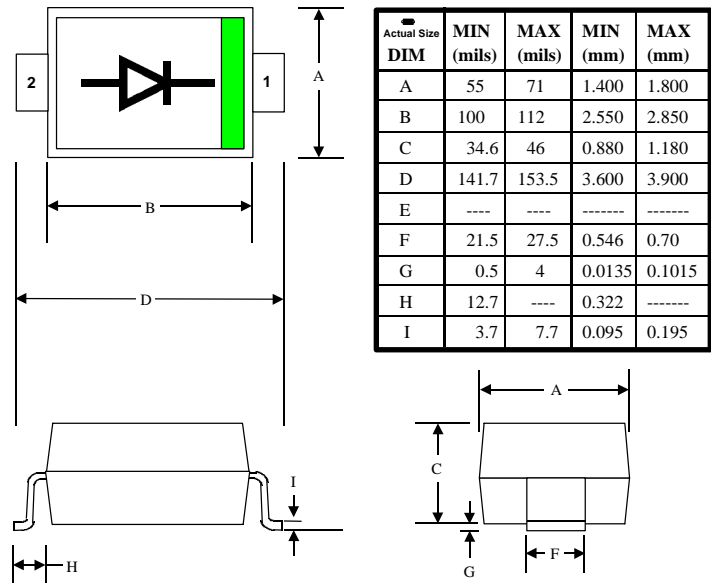


### Electrical Characteristics $T_A=25^\circ\text{C}$ unless otherwise noted

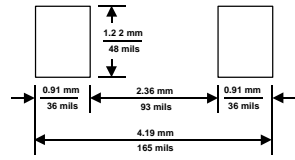
Symbol	Characteristics	Test Conditions	Min.	Max.	Units
$V_Z$	Zener Voltage	$I_{ZT} = 50\mu\text{A}$ D.C	9.50	10.50	V
$I_R$	Reverse Leakage	$V_R = 7.6\text{V}$		1.0	$\mu\text{A}$
$V_F$	Forward Voltage	$I_F = 10\text{mA}$		900	mV
$\Delta V_Z$	Delta Zener Voltage (Note 2)	$I_{ZT} = 100\mu\text{A}$ to $10\mu\text{A}$		100	mV

**SOD-123 PACKAGE**  
 PACKAGE CODE = (D6)  
 Fairchild Semiconductor's Criteria

Corrected March 11, 1998



Actual Size DIM	MIN (mils)	MAX (mils)	MIN (mm)	MAX (mm)
A	55	71	1.400	1.800
B	100	112	2.550	2.850
C	34.6	46	0.880	1.180
D	141.7	153.5	3.600	3.900
E	----	----	-----	-----
F	21.5	27.5	0.546	0.70
G	0.5	4	0.0135	0.1015
H	12.7	----	0.322	-----
I	3.7	7.7	0.095	0.195



SOD-123 LAND PADS

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EnSigna™	µC™	OCX™	RapidConfigure™	TruTranslation™
FACT™	ImpliedDisconnect™	OCXPro™	RapidConnect™	UHC™
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Programmable Active Droop™		PACMAN™	SPM™	

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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